## CNZ2253 (ON2253)

## Reflective Photosensor

## $\square$ Overview

CNZ2253 is a photosensor detecting the change of reflective light in which a high efficiency GaAs infrared light emitting diode is used as the light emitting element, and a high sensitivity Si Darlington phototransistor is used as the light detecting element. The two elements are located parallel in the same direction and objects are detected when passing in front of the device.

## Features

- High sensitivity
- Small size and light weight
- Applications
- Detection of paper, film and cloth - Optical mark reading
- Detection of position and edge - Detection of coin and bill
- Start, end mark detection of magnetic tape

Absolute Maximum Ratings $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

|  |  |  |  | Parameter |
| :--- | :--- | :---: | :---: | :---: |
| Input (Light <br> emitting diode) | Severse voltage (DC) | $\mathrm{V}_{\mathrm{R}}$ | 3 | V |
|  | Forward current (DC) | $\mathrm{I}_{\mathrm{F}}$ | 50 | mA |
|  | Power dissipation | $\mathrm{P}_{\mathrm{D}}{ }^{* 1}$ | 75 | mW |
| Output (Photo <br> transistor) | Collector to emitter voltage | $\mathrm{V}_{\mathrm{CEO}}$ | 20 | V |
|  | Emitter to collector voltage | $\mathrm{V}_{\mathrm{ECO}}$ | 5 | V |
|  | Collector current | $\mathrm{I}_{\mathrm{C}}$ | 30 | mA |
|  | Collector power dissipation | $\mathrm{P}_{\mathrm{C}}{ }^{* 2}$ | 100 | mW |
| Temperature | Operating ambient temperature | $\mathrm{T}_{\text {opr }}$ | -25 to +85 | ${ }^{\circ} \mathrm{C}$ |
|  | Storage temperature | $\mathrm{T}_{\text {stg }}$ | -30 to +100 | ${ }^{\circ} \mathrm{C}$ |


${ }^{* 1}$ Input power derating ratio is $1.0 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ at $\mathrm{Ta} \geq 25^{\circ} \mathrm{C}$.
${ }^{* 2}$ Output power derating ratio is $1.34 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ at $\mathrm{Ta} \geq 25^{\circ} \mathrm{C}$.

Electrical Characteristics $\left(\mathrm{Ta}=25^{\circ} \mathrm{C}\right)$

| Parameter |  | Symbol | Conditions | min | typ | max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input characteristics | Forward voltage (DC) | $\mathrm{V}_{\mathrm{F}}$ | $\mathrm{I}_{\mathrm{F}}=50 \mathrm{~mA}$ |  | 1.2 | 1.5 | V |
|  | Reverse current (DC) | $\mathrm{I}_{\mathrm{R}}$ | $\mathrm{V}_{\mathrm{R}}=3 \mathrm{~V}$ |  |  | 10 | $\mu \mathrm{A}$ |
|  | Capacitance between terminals | $\mathrm{C}_{\text {t }}$ | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 50 |  | pF |
| Ouput charaterisics | Collector cutoff current | $\mathrm{I}_{\text {CEO }}$ | $\mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}$ |  |  | 0.5 | $\mu \mathrm{A}$ |
| Transfer characteristics | Collector current | $\mathrm{I}_{\mathrm{C}}{ }^{* 1 * 2}$ | $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ | 3 |  | 30 | mA |
|  | Response time | $\mathrm{tr}^{* 3}, \mathrm{t}_{\mathrm{f}}{ }^{*}$ | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ |  | 150 |  | $\mu \mathrm{s}$ |
|  | Collector to emitter saturation voltage | $\mathrm{V}_{\mathrm{CE} \text { (sat) }}$ | $\mathrm{I}_{\mathrm{F}}=50 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}$ |  |  | 1.5 | V |

${ }^{* 1} I_{C}$ classifications

| Class | Q | R | S |
| :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\mathrm{C}}(\mathrm{mA})$ | 3 to 9 | 6 to 18 | 12 to 30 |

${ }^{* 3}$ Time required for the collector current to increase from $10 \%$ to $90 \%$ of its final value.
${ }^{* 4}$ Time required for the collector current to decrease from $90 \%$ to $10 \%$ of its initial value.
*2 Transfer characteristics measurement circuit (Ambient light is shut off completely)


Standard white paper (Reflective ratio 90\%)

Note) The part number in the parenthesis shows conventional part number.








$I_{C}-d$


# $\triangle$ Caution for Safety 

Gallium arsenide material (GaAs) is used in this product.

## $\triangle$ DANGER

Therefore, do not burn, destroy, cut, crush, or chemically decompose the product, since gallium arsenide material in powder or vapor form is harmful to human health.
Observe the relevant laws and regulations when disposing of the products. Do not mix them with ordinary industrial waste or household refuse when disposing of GaAs-containing products.

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